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TRANSMITTAL FORM (to be used for all correspondence after initial filing)	Applicati n Number	08/788,560
	Filing Date	January 24, 1997
	First Named Inventor	Shunpei YAMAZAKI et al.
	Group Art Unit	2811
	Examiner Name	O. Nadav
Total Number of Pages in This Submission	Attorney Docket Number	0756-1626

ENCLOSURES (check all that apply)		
<input type="checkbox"/> Fee Transmittal Form <input type="checkbox"/> Fee Attached <input checked="" type="checkbox"/> Amendment / Reply <input checked="" type="checkbox"/> After Final <input type="checkbox"/> Affidavits/declaration(s) <input type="checkbox"/> Extension of Time Request <input type="checkbox"/> Express Abandonment Request <input type="checkbox"/> Information Disclosure Statement <input type="checkbox"/> Certified Copy of Priority Document(s) <input type="checkbox"/> Response to Missing Parts/ Incomplete Application <input type="checkbox"/> Response to Missing Parts under 37 CFR 1.52 or 1.53	<input type="checkbox"/> Assignment Papers (for an Application) <input type="checkbox"/> Drawing(s) <input type="checkbox"/> Declaration and Power of Attorney <input type="checkbox"/> Licensing-related Papers <input type="checkbox"/> Petition <input type="checkbox"/> Petition to Convert to a Provisional Application <input type="checkbox"/> Power of Attorney, Revocation Change of Correspondence Address <input type="checkbox"/> Terminal Disclaimer <input type="checkbox"/> Request for Refund <input type="checkbox"/> CD, Number of CD(s) Remarks <input checked="" type="checkbox"/> The Commissioner is hereby authorized to charge any additional fees required or credit any overpayments to Deposit Account No. 501 2280 for the above identified docket number.	<input type="checkbox"/> After Allowance Communication to Group <input type="checkbox"/> Appeal Communication to Board of Appeals and Interferences <input type="checkbox"/> Appeal Communication to Group (Appeal Notice, Brief, Reply Brief) <input type="checkbox"/> Proprietary Information <input type="checkbox"/> Status Letter <input checked="" type="checkbox"/> Other Enclosures 1. Change of Correspondence Address Form 2. 3. 4. 5. 6.

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Firm or Individual name	Eric J. Robinson, Reg. No. 38,285 Robinson Intellectual Property Law Office, P.C. PMB 955 21010 Southbank Street Potomac Falls, VA 20165
Signature	
Date	August 1, 2002

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Packet No. 0756-1626

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

) Art Unit: 2811

Shunpei YAMAZAKI et al.

) Examiner: O. Nadav

Serial No. 08/788,560

Filed: January 24, 1997

For: SEMICONDUCTOR DEVICE AND

METHOD OF FORMING THE SAME)

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AMENDMENT

Honorable Commissioner of Patents

Washington, D.C. 20231

Sir:

In response to the Office Action dated May 1, 2002, please amend the above-
identified application as follows:

IN THE CLAIMS:

Please amend claims 78, 84, 90, 96, 102, 110, 118, 126, 134, 140, 146, and
152 as follows:

78. (Amended) A semiconductor device comprising:

a semiconductor layer including a channel region and source and drain
regions in contact with said channel region at a source-channel boundary and a drain-
channel boundary, respectively;

a gate electrode adjacent to said channel region with a gate insulating film
interposed therebetween; and

a region formed in the vicinity of at least one of said source-channel
boundary and said drain-channel boundary in said semiconductor layer, said region
containing one or more elements selected from the group consisting of carbon, nitrogen,
and oxygen at a concentration of 1×10^{19} atoms/cm³ or more,

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